



Monitoring (1.1.6)

Silicon Radiation and Temperature Monitoring

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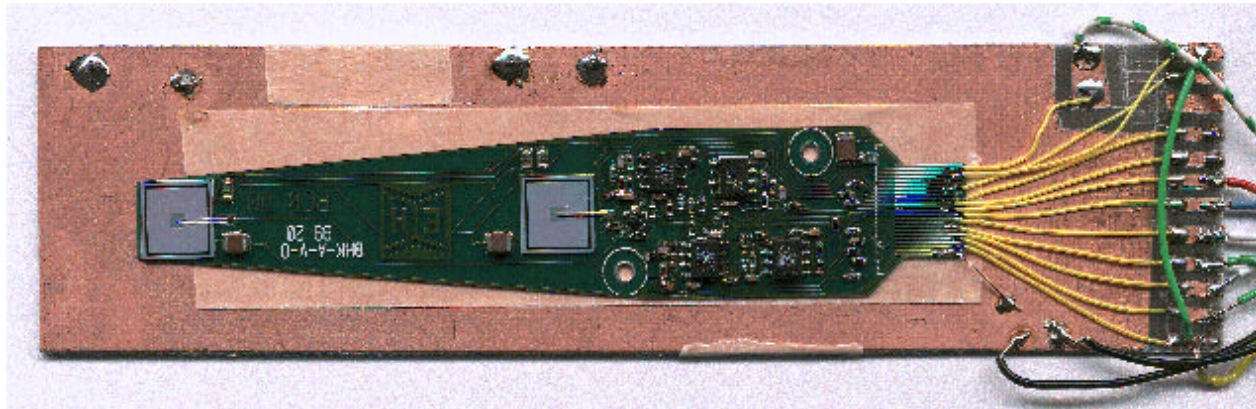
Radiation and Temperature Monitoring

- The basic philosophy is to build on Run I I a experience and make only minor changes
- Radiation monitoring will reproduce the existing system within the new geometry
- Temperature monitoring will reproduce the existing system, with an additional system for L0/L1.



Radiation monitoring

- Currently there are two systems
Beam Loss Monitors from Beams Division
Silicon diodes mounted on F and H disks

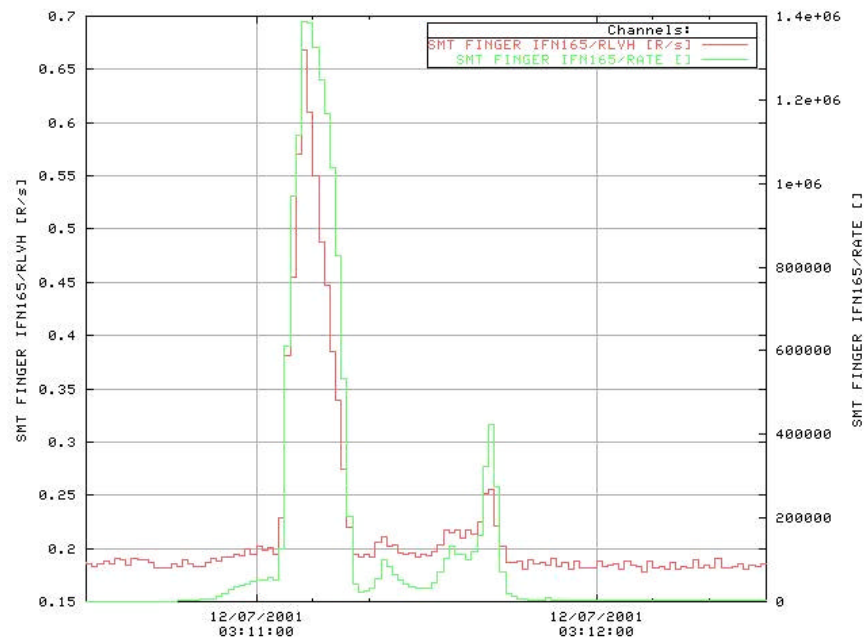


Radiation monitor finger as mounted on F or H disk



Radiation Monitoring

- Silicon diodes are being made as part of the sensor order with Hamatsu



Sample radiation loss event as measured in one of radiation monitor fingers



Temperature Monitoring

- Devices used are thin film platinum resistors, RTDs.
- Run I I a system will be reproduced, with an RTD on each hybrid.

Read out through the 1553 system

The temperature value interlocks the power to each hybrid.



Temperature Monitoring

- A second temperature monitoring system will monitor the L0 sensors (since, for L0 the hybrids are not close to the sensors)
- This system will also provide more accurate monitoring of other parts of the detector
- RTDs are read out through commercial modules via the D0 cryo system.